PRELIMINARY SPEC

## OVAL SOLID STATE LAMP

Part Number: WP5603SIDL/SD/J HYPER ORANGE

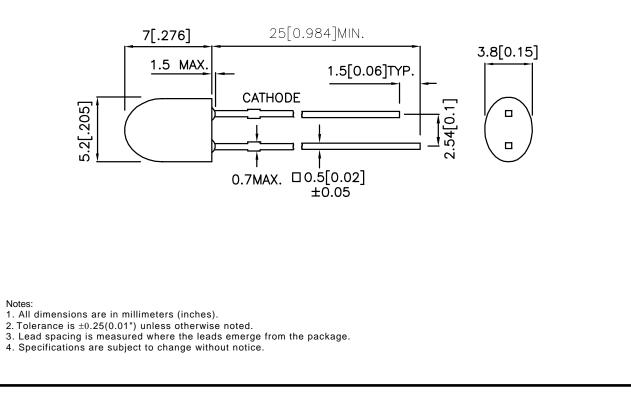
### Features

OUTSTNDING MATERIAL EFFICIENCY.RELIABLE AND RUGGED.I.C. COMPATIBLE/LOW CURRENT CAPABILITY.RoHS COMPLIANT.

### Description

The Super Bright device is based on a light emitting diode chip made from AlGaInP and bonded on silicon substrate.

### **Package Dimensions**



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#### **Selection Guide** lv (mcd) [2] @ 20mA Viewing Angle [1] Part No. Dice Lens Type 201/2 Min. TYP. 100°(H) WP5603SIDL/SD/J HYPER ORANGE (AlGaInP) **RED SEMI DIFFUSED** 1800 3600 50°(V)

Notes:

1.  $\theta$ 1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

2. Luminous intensity/ luminous Flux: +/-15%.

### Electrical / Optical Characteristics at TA=25°C

Symbol	Parameter	Device	Тур.	Max.	Units	Test Conditions
λpeak	Peak Wavelength	Hyper Orange	640		nm	IF=20mA
λD [1]	Dominant Wavelength	Hyper Orange	630		nm	IF=20mA
Δλ1/2	Spectral Line Half-width	Hyper Orange	25		nm	IF=20mA
С	Capacitance	Hyper Orange	27		pF	VF=0V;f=1MHz
VF [2]	Forward Voltage	Hyper Orange	2.2	2.8	V	IF=20mA
Ir	Reverse Current	Hyper Orange		10	uA	VR = 5V

Notes:

1.Wavelength: +/-1nm.

2. Forward Voltage: +/-0.1V.

## Absolute Maximum Ratings at TA=25°C

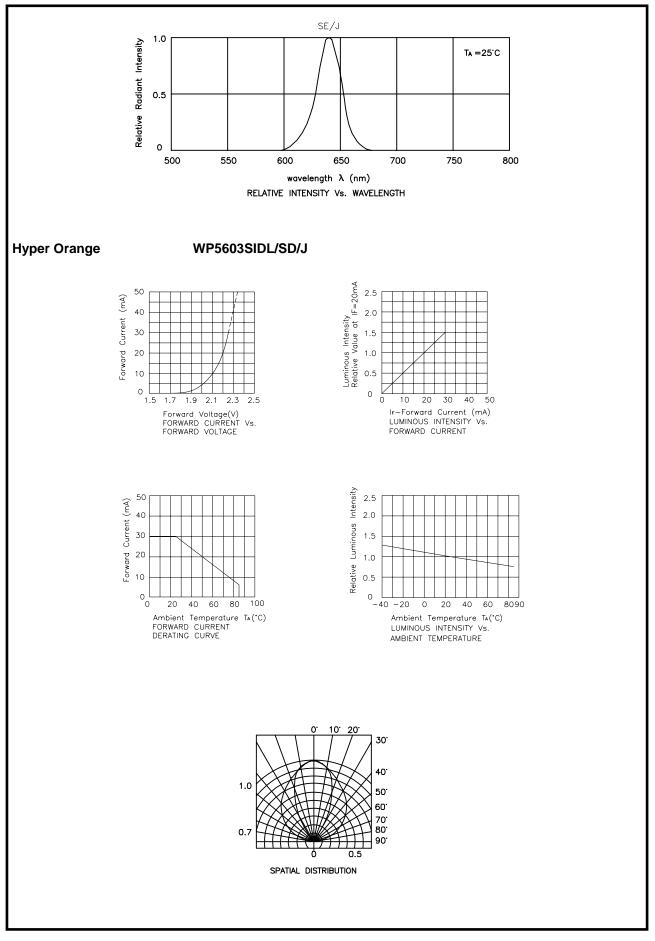
Parameter	Hyper Orange	Units		
Power dissipation	84	mW		
DC Forward Current	30	mA		
Peak Forward Current [1]	150	mA		
Reverse Voltage	5	V		
Operating/Storage Temperature	-40°C To +85°C			
Lead Solder Temperature [2]	260°C For 3 Seconds			
Lead Solder Temperature [3]	260°C For 5 Seconds			

Notes:

1. 1/10 Duty Cycle, 0.1ms Pulse Width.

2. 2mm below package base.

3. 5mm below package base.



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